

Ver 1.1

Radiation Hardened 16-Channel Current Negative Driver

Datasheet

Part Number: BM2711MQRH



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1. Unique Features

- 1) 16 Channels
- 2) Supply Voltage (V_{DD})4.5V~5.5V
- 3) Higher than 200mA driver ability for each channel
- 4) Dual enable control signal
- 5) T_A-55°C~125°C
- 6) Package.....CQFP64
- 7) Total Ionizing Dose ≥ 100 krad (Si)
- 8) The Single Event Latch-up Immunity



2. General Description

The device implements 16-channel switch instruction driver. Each channel can be controlled by two independent signals. When these two signals are simultaneously active (high level), the instruction signal will be presented at the output. The power loop can be switched on or off by the instruction signal. Each channel's pre-driver and post-switch circuits are designed by redundant structure that can improve circuit's reliability and robustness. There is an excellent isolation between each channel. If one channel is abnormal, the other channels won't be affected and can output exactly.

3. Pin Description

The pins description of BM2711MQRH is shown in figure 1, Table 1.

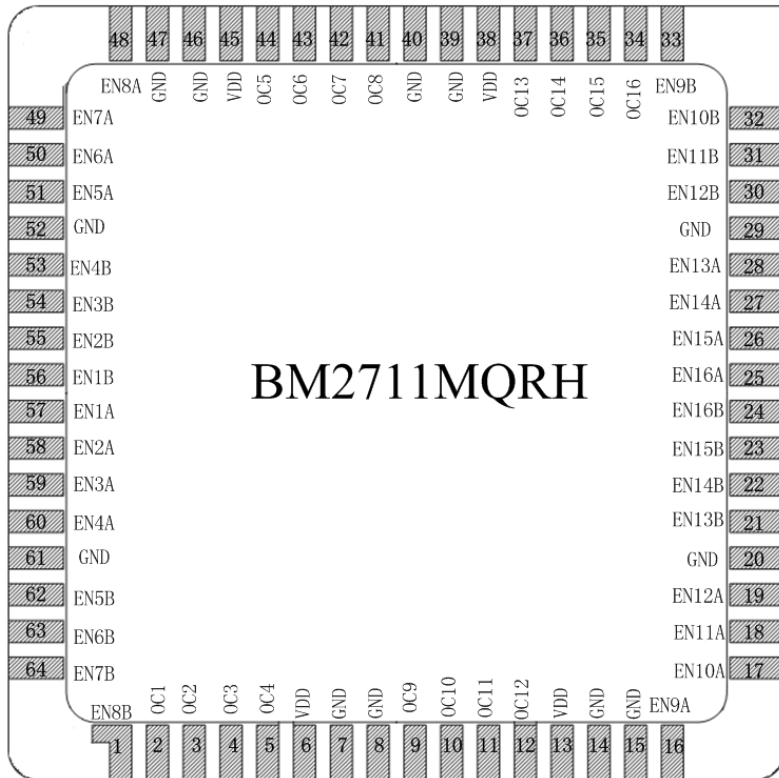


Figure1. BM2711MQRH Pin Configuration (Top View)

Table1. BM2711MQRH Pin Configuration

Pin	Description	Symbol	Pin	Description	Symbol
1	8 th B Input	EN8B	33	9 th B Input	EN9B
2	1 st Output	OC1	34	16 th Output	OC16
3	2 nd Output	OC2	35	15 th Output	OC15
4	3 rd Output	OC3	36	14 th Output	OC14
5	4 th Output	OC4	37	13 th Output	OC13
6	Power Supply	VDD	38	Power Supply	VDD
7	Ground	GND	39	Ground	GND
8	Ground	GND	40	Ground	GND
9	9 th Output	OC9	41	8 th Output	OC8
10	10 th Output	OC10	42	7 th Output	OC7
11	11 th Output	OC11	43	6 th Output	OC6
12	12 th Output	OC12	44	5 th Output	OC5
13	Power Supply	VDD	45	Power Supply	VDD

Pin	Description	Symbol	Pin	Description	Symbol
14	Ground	GND	46	Ground	GND
15	Ground	GND	47	Ground	GND
16	9 th A Input	EN9A	48	8 th A Input	EN8A
17	10 th A Input	EN10A	49	7 th A Input	EN7A
18	11 th A Input	EN11A	50	6 th A Input	EN6A
19	12 th A Input	EN12A	51	5 th A Input	EN5A
20	Ground	GND	52	Ground	GND
21	13 th B Input	EN13B	53	4 th B Input	EN4B
22	14 th B Input	EN14B	54	3 rd B Input	EN3B
23	15 th B Input	EN15B	55	2 nd B Input	EN2B
24	16 th B Input	EN16B	56	1 st B Input	EN1B
25	16 th A Input	EN16A	57	1 st A Input	EN1A
26	15 th A Input	EN15A	58	2 nd A Input	EN2A
27	14 th A Input	EN14A	59	3 rd A Input	EN3A
28	13 th A Input	EN13A	60	4 th A Input	EN4A
29	Ground	GND	61	Ground	GND
30	12 th B Input	EN12B	62	5 th B Input	EN5B
31	11 th B Input	EN11B	63	6 th B Input	EN6B
32	10 th B Input	EN10B	64	7 th B Input	EN7B

4. Function Description

4.1 Function Block Diagram

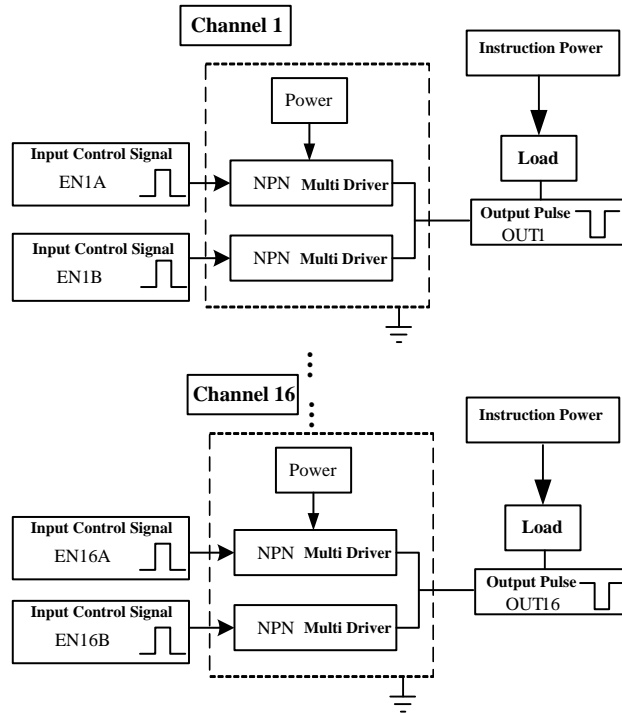


Figure 2. Function Block Diagram

4.2 Truth Table

Table 2. Truth Table for Single Channel

Input		Output
EN _i A	EN _i B	OC _i
0	0	High-Z
0	1	High-Z
1	0	High-Z
1	1	0

Note: The table2 indicates the logic relationship between output and input of each channel; the supply current will be different when input signals are in different logic configuration, and the details will be shown in section 6.3.

4.3 Logical Relationships

Table 3. Logical Relationships

Input ENiA&ENiB	Output															
	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
EN1A&EN1B	1	0	×	×	×	×	×	×	×	×	×	×	×	×	×	×
EN2A&EN2B	1	×	0	×	×	×	×	×	×	×	×	×	×	×	×	×
EN3A&EN3B	1	×	×	0	×	×	×	×	×	×	×	×	×	×	×	×
EN4A&EN4B	1	×	×	×	0	×	×	×	×	×	×	×	×	×	×	×
EN5A&EN5B	1	×	×	×	×	0	×	×	×	×	×	×	×	×	×	×
EN6A&EN6B	1	×	×	×	×	×	0	×	×	×	×	×	×	×	×	×
EN7A&EN7B	1	×	×	×	×	×	×	0	×	×	×	×	×	×	×	×
EN8A&EN8B	1	×	×	×	×	×	×	×	0	×	×	×	×	×	×	×
EN9A&EN9B	1	×	×	×	×	×	×	×	×	0	×	×	×	×	×	×
EN10A&EN10B	1	×	×	×	×	×	×	×	×	×	0	×	×	×	×	×
EN11A&EN11B	1	×	×	×	×	×	×	×	×	×	×	0	×	×	×	×
EN12A&EN12B	1	×	×	×	×	×	×	×	×	×	×	×	0	×	×	×
EN13A&EN13B	1	×	×	×	×	×	×	×	×	×	×	×	×	0	×	×
EN14A&EN14B	1	×	×	×	×	×	×	×	×	×	×	×	×	×	0	×
EN15A&EN15B	1	×	×	×	×	×	×	×	×	×	×	×	×	×	×	0
EN16A&EN16B	1	×	×	×	×	×	×	×	×	×	×	×	×	×	×	0

¹ × indicate the channel i's output is link to the channel i's input only.
² There are 2 channels can be driven at the same time.(When the output drive current is 200mA)

5. Electrical Characteristic

5.1 Absolute Maximum Ratings

Parameter	Symbol	Data		Unit
		Min	Max	
Supply Voltage	V_{DD}	-0.3	12	V
Load Voltage	V_{CC}	-0.3	50	V
Output Current	I_O	0	360	mA
Power Consumption	P_T	0	1.5	W
Input Signal Range	V_{EN}	0	12	V
Storage Temperature Range	T_{stg}	-65	+150	°C
Lead Temperature (10s)	T_h	—	300	°C
Junction Temperature	T_j	—	150	°C

5.2 Recommended Operating Conditions

Parameter	Symbol	Data	Unit
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		Min	Max	
Output Current	V_{DD}	4.5	5.5	V
Power Dissipation	V_{CC}	3.3	33	V
Output Current	I_O	0	200	mA
Input Voltage	V_{EN}	0	5.5	V
Temperature Range	T_A	-55	125	°C

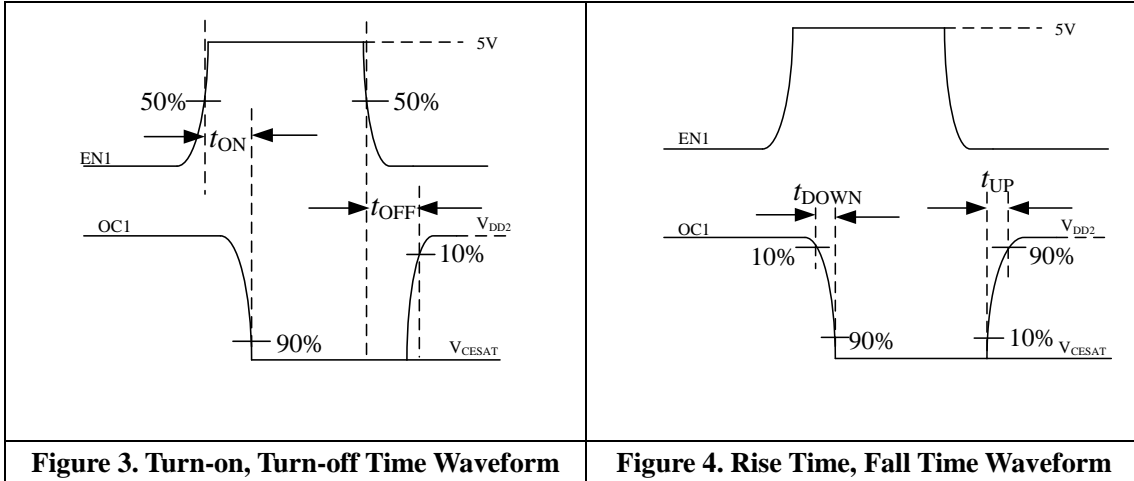
5.3 Electrical Specifications

$V_{CC}=28V$, $V_{DD}=4.5V$, $-55^{\circ}C \leq T_A \leq 125^{\circ}C$, unless otherwise noted

Table 4. Electronic Specifications

Parameter	Symbol	Condition ($V_{DD}=5V$, $GND=0V$, $-55^{\circ}C \leq T_A \leq 125^{\circ}C$, unless otherwise noted)	Data		Unit
			Min	Max	
Output Leakage Current	I_{OD}	$V_{ENXA}=V_{ENXB}=0.6V$ ($x=1 \dots 16$), $R_L=120\Omega$, Measured Output $ I_{ODX} $ (Measured all 16 channels)	--	20	uA
		$V_{ENXA}=0.6V$, $V_{ENXB}=3.0V$ ($x=1 \dots 16$), $R_L=120\Omega$, Measured Output $ I_{ODX} $ (Measured all 16 channels)	--	20	
		$V_{ENXA}=3.0V$, $V_{ENXB}=0.8V$ ($x=1 \dots 16$), $R_L=120\Omega$, Measured Output $ I_{ODX} $ (Measured all 16 channels)	--	20	
Output Saturation Voltage Drop	V_{CESAT}	$V_{ENXA}=3.0V$, $V_{ENXB}=3.0V$ ($x=1 \dots 16$), $I_{OL}=200mA$, Measured Output $ V_{OUTX} $ (Measured all 16 channels)	--	1.2	V
Output Current	I_O	$V_{ENXA}=3.0V$, $V_{ENXB}=3.0V$ ($x=1 \dots 16$), $V_{CESAT}=1.2V$, Measured Output $ I_{OUTX} $ (Measured all 16 channels)	200	--	mA
High Level Input Voltage	V_{IH}	$I_{OL}=200mA$, $V_{CESAT}=1.2V$	3.0	--	V
Low Level Input Voltage	V_{IL}		--	0.6	V
High Level Input Current	I_{IH}	$V_{ENXA}=3.0V$, $V_{ENXB}=3.0V$ ($x=1 \dots 16$) ($V_{ENYA}=V_{ENYB}=0.8V$, other channels is not x), $I_{OL}=200mA$, Measured Input $ I_{IHx} $ (Measured all 16 channels)	--	2	mA
Static Current	I_D	$V_{ENXA}=0.6V$, $V_{ENXB}=0.6V$ ($x=1 \dots 16$) ($V_{ENYA}=V_{ENYB}=0.6V$, other channels is not x), Measured Power	--	1	mA
Operating Current	I_{VDD}	$V_{ENXA}=3.0V$, $V_{ENXB}=3.0V$ ($x=1 \dots 16$) ($V_{ENYA}=V_{ENYB}=0.8V$, other channels is not x), $I_{OL}=200mA$, Measured Power $ I_{VDD} $ (Measured all 16 channels)	--	50	mA
Turn-on Time	t_{ON}	$f=1kHz$, $R_L=120\Omega$, Measured according to figure 3	--	10	us
Turn-off Time	t_{OFF}	$f=1kHz$, $R_L=120\Omega$, Measured according to figure 3	--	70	us
Rise Time	t_{UP}	$f=1kHz$, $R_L=120\Omega$, Measured according to figure 4	--	65	us

Parameter	Symbol	Condition	Data		Unit
		($V_{DD}=5V$, $GND=0V$, $-55^{\circ}C \leq TA \leq 125^{\circ}C$, unless otherwise noted)	Min	Max	
Fall Time	t_{DOWN}	$f=1kHz$, $R_L=120\Omega$, Measured according to figure 4	--	8	us



5.4 ESD Cautions

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 2000 V readily accumulated on the human body fits the 2nd Level of 3015 in GJB548B-2005.

6. Typical Application

6.1 Typical Application Circuit

The typical application circuit of BM2711MQRH is shown in figure 5.

In figure 5, V_{DD} is the device power supply voltage, GND is ground of power supply, R_i is instruction load, the end of R_i are connected to the OC_i and instruction power(V_{CC}) individual.

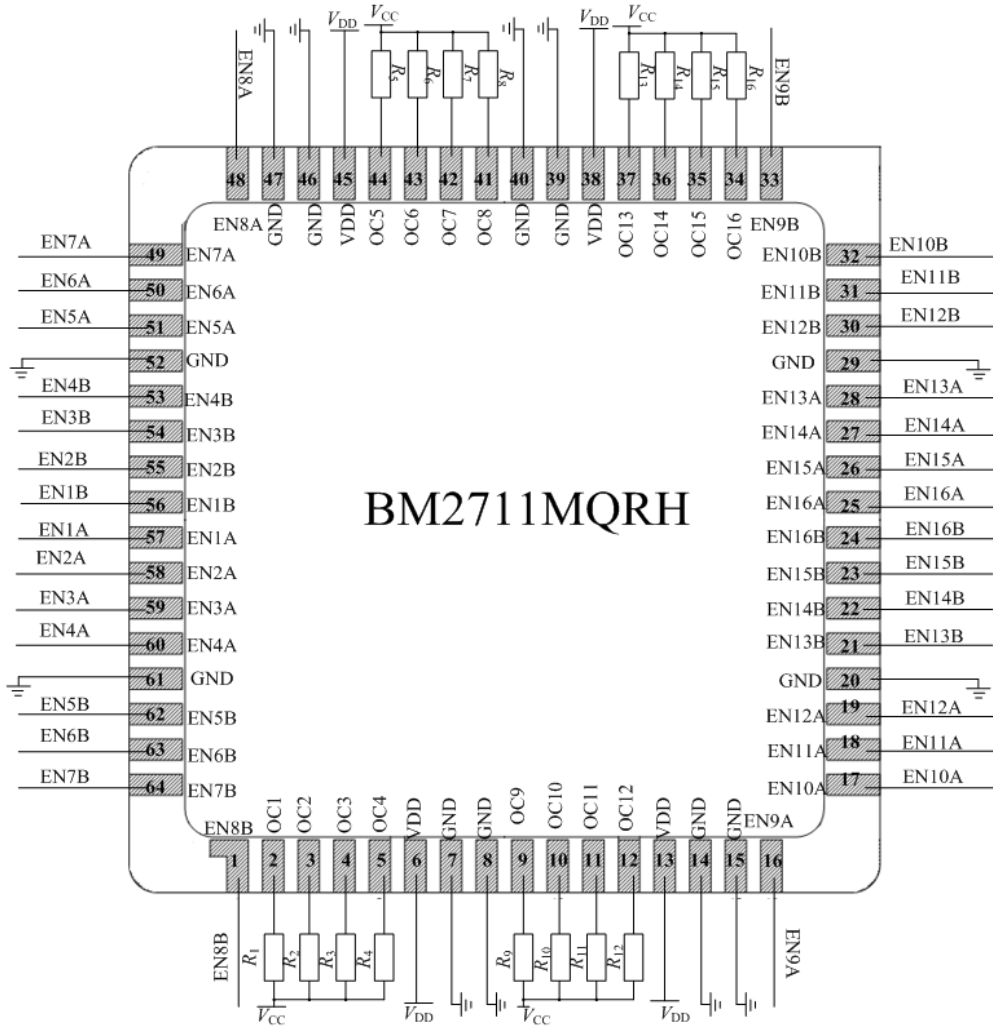


Figure 5. BM2711MQRH typical application circuit

6.2 Power Consumption Expression

The number of active channel is limited by the device's maximum power consumption.

The device's power consumption is composed by three parts: the power consumption of input drives, power supplies and output drives. And the device's power consumption expression can be written as below:

$$P=I_{EN} \times V_{EN}+I_{VDD} \times V_{DD}+I_O \times V_{CESAT}$$

The maximum power consumption of the device is 1.5W, and each channel's power consumption could be derived by the parameters of the electrical characteristics table as following:

$$P1=0.002 \times 5.5 \times 2+0.05 \times 5.5+0.2 \times 1.2=0.537W$$

So the number of active channels is two because the whole power consumption of

the device is all channels' power summation.

6.3 Supply Current with Input Signals

The typical work condition of BM2711MQRH is:

$ENiA=ENiB=1$: The channel i is in ON-state, output terminal OCi output is in low level and it can provide driver current;

$ENiA\&ENiB=0$: The channel i is in OFF-state, output terminal OCi output is in high level (load terminal voltage).

The relationship with supply current and input signal is:

1) $ENiA=ENiB=1$: The forestage driver circuit of part A and part B of channel i is in ON-state, and the supply current is about 40mA at room temperature. Output driver transistors of part A and part B are turned on, output terminal can provides driver current.

2) $ENiA =1, ENiB=0$: The forestage driver circuit of part A and part B of channel i is in OFF-state, and there is no supply current. Output driver transistors of part A and part B are turned off, output terminal is turned off.

3) $ENiA =0, ENiB=1$: The forestage driver circuit of part A of channel i is in OFF-state, but there is an access between the forestage driver circuit of part B of channel i and GND, and the supply current is about 20mA at room temperature. Output driver transistors of part A and part B of channel i are turned off due to the output driver transistors' series connection, so output terminal of channel i is also in OFF-state.

The relationship between supply current and single channel input voltage level is as follows:

Input Voltage Level		Supply Current	Output
ENiA	ENiB	I_{VDD}	OCi
0	0	$\leq 1mA$	High-Z
0	1	$\leq 25mA$	High-Z
1	0	$\leq 1mA$	High-Z
1	1	$\leq 1mA$	0

7. Package Outline Dimensions

7.1 BM2711MQRH's packaging is CQFP64 which is shown as follows.

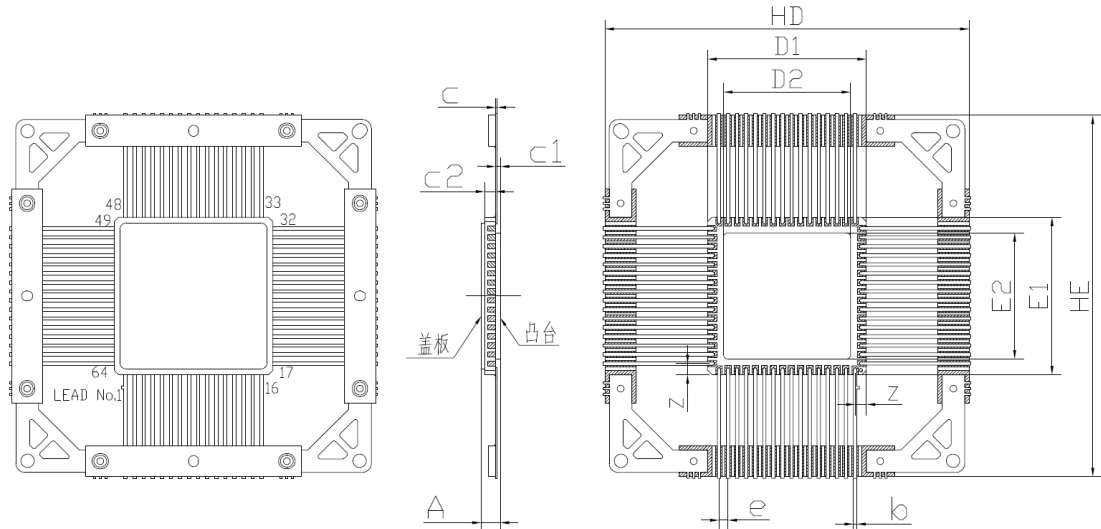


Figure 6. BM2711MQRH's Packaging(CQFP64)

Table 5. Dimensions

Symbol	Data(Unit: mm)		
	Min	typical	Max
A	1.85	—	2.50
b	0.3	—	0.46
c	0.09	—	0.21
c1	0.35	—	0.57
c2	1.05	—	1.93
HD/HE	39.90	—	41.60
D1/E1	17.40	—	18.15
D2/E2	13.95	—	14.55
e	—	1.016	—
Z	1.09	—	1.45

7.2 The Outline dimensions of CQFP64 which is cut for use.

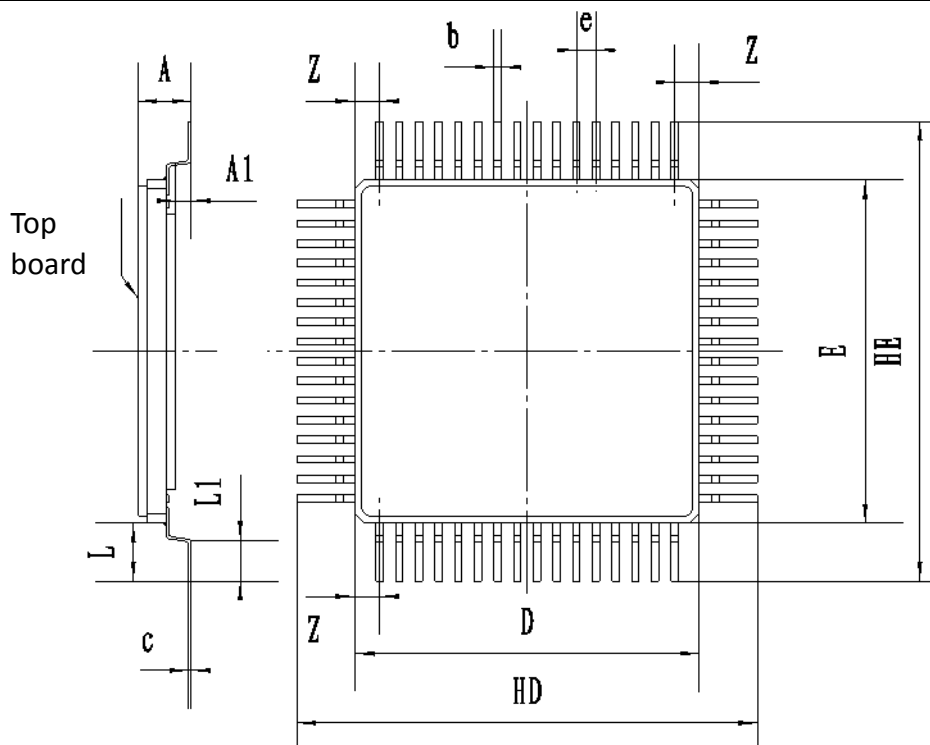


Figure 7. Cutting Forming Diagram

Table 6. Cutting Forming Dimensions

Symbol	Data (Unit: mm)		
	Min	typical	Max
A	2.3		3.2
A1	0.5	0.75	1.01
b		0.381	
c		0.152	
e		1.016	
Z		1.27	
D/E		17.78	
HD/HE	21.58	22.78	23.98
L1	1.25	1.5	1.75
L	2.0	2.5	3.0

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